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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MMSTA63/MMSTA64

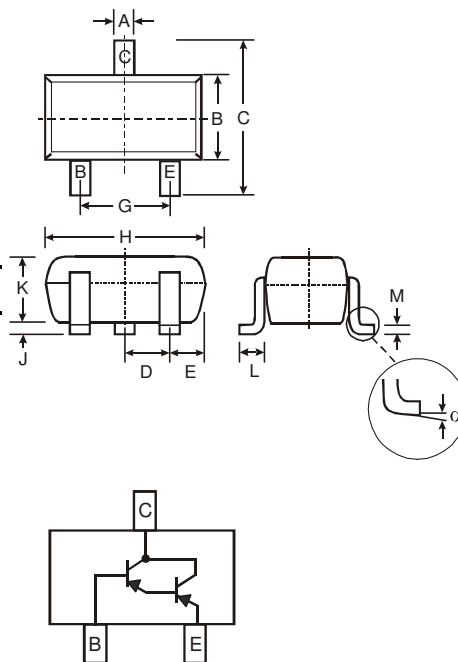
PNP SURFACE MOUNT DARLINGTON TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (MMSTA13/MMSTA14)
- Ultra-Small Surface Mount Package
- Ideal for Medium Power Amplification and Switching
- High Current Gain
- **Lead Free/RoHS Compliant (Note 2)**
- **"Green" Device (Note 3 and 4)**

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA63 Marking K2E, K3E, See Page 3
- MMSTA64 Marking K3E, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

Maximum Ratings @T_A = 25°C unless otherwise specified

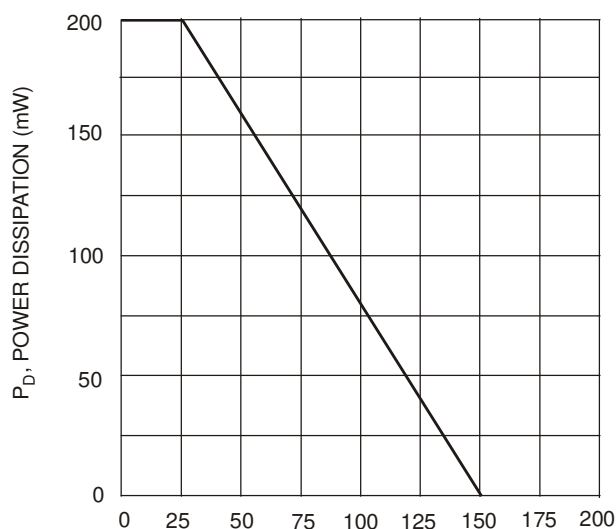
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-30	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V _{EBO}	-10	V
Collector Current - Continuous	I _C	-500	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. No purposefully added lead.
 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php
 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Electrical Characteristics @T_A = 25°C unless otherwise specified

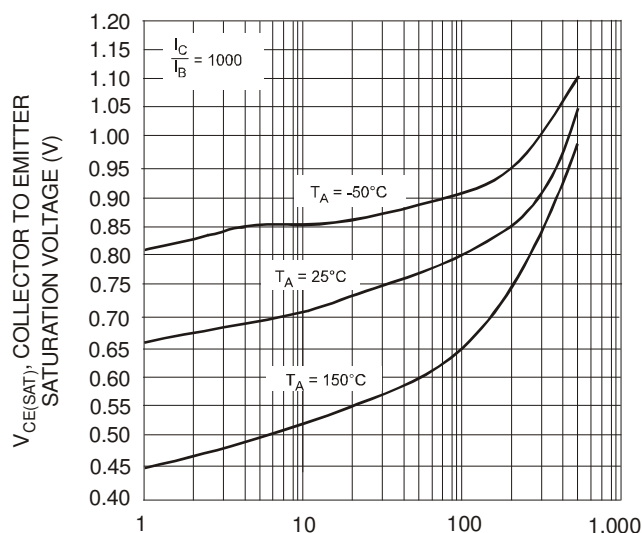
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-30	—	V	I _C = -100μA V _{BE} = 0V
Collector Cutoff Current	I _{CBO}	—	-100	nA	V _{CB} = -30V, I _E = 0
Emitter Cutoff Current	I _{EBO}	—	-100	nA	V _{EB} = -10V, I _C = 0
ON CHARACTERISTICS (Note 5)					
DC Current Gain	MMSTA63 MMSTA64 MMSTA63 MMSTA64	h _{FE}	5,000 10,000 10,000 20,000	—	I _C = -10mA, V _{CE} = -5.0V I _C = -10mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	-1.5	V	I _C = -100mA, I _B = -100μA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	-2.0	V	I _C = -100mA, V _{CE} = -5.0V
SMALL SIGNAL CHARACTERISTICS					
Current Gain-Bandwidth Product	f _T	125	—	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 100MHz

Notes: 5. Short duration pulse test used to minimize self-heating effect.



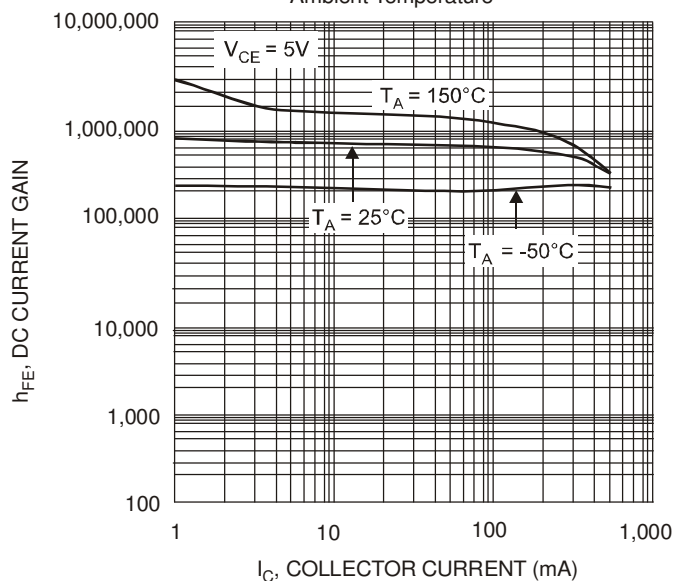
T_A, AMBIENT TEMPERATURE (°C)

Fig. 1, Max Power Dissipation vs. Ambient Temperature



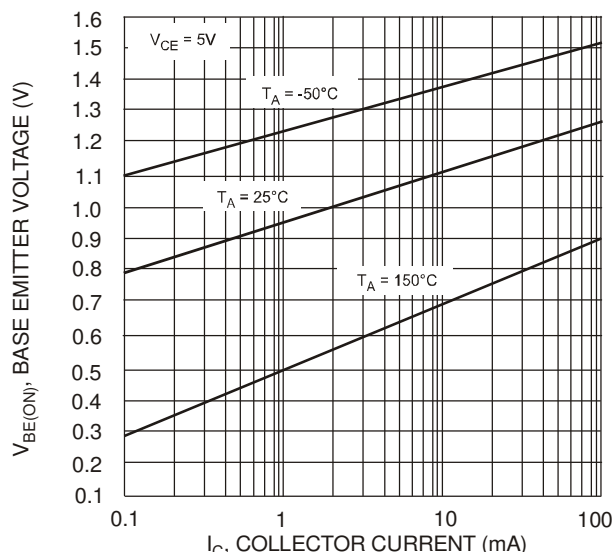
I_C, COLLECTOR CURRENT (mA)

Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current



I_C, COLLECTOR CURRENT (mA)

Fig. 3, DC Current Gain vs. Collector Current



I_C, COLLECTOR CURRENT (mA)

Fig. 4, Base Emitter Voltage vs. Collector Current

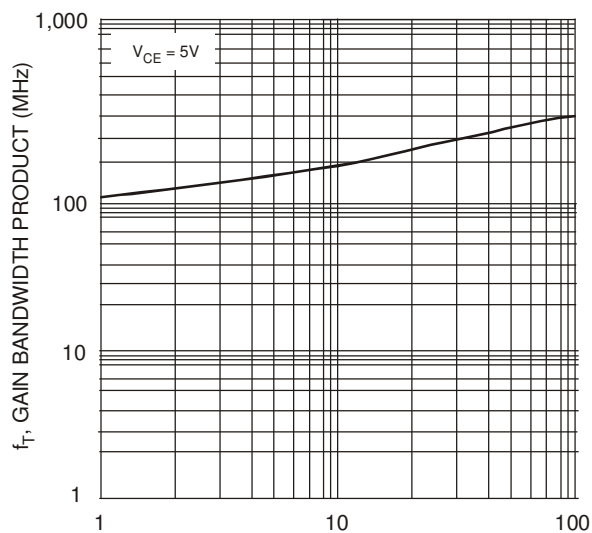


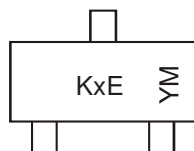
Fig. 5, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 4 & 6)

Device	Packaging	Shipping
MMSTA63-7-F	SOT-323	3000/Tape & Reel
MMSTA64-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



KxE = Product Type Marking Code, e.g. K2E = MMSTA63
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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